

(1) Quartz Crystal Division of Seiko Instruments Inc. and affiliates, which is responsible for manufacturing the products described in this catalogue, holds ISO 9001 and ISO 14001 certification

(2) SII Crystal Technology Inc. Tochigi site holds IATF 16949 certification.



www.sii-crystal.com

#### Seiko Instruments Inc.

Electronic Components Sales Head Office 1-8, Nakase, Mihamaku, Chiba-shi, Chiba 261-8507, Japan Telephone:+81-43-211-1207 Facsimile:+81-43-211-8030 E-mail:component@sii.co.jp

<Manufacturer> SII Crystal Technology Inc. 1110, Hirai-cho, Tochigi-shi, Tochigi 328-0054, Japan

Seiko Instruments (H.K.) Ltd. 4-5/F, Wyler Centre 2, 200 Tai Lin Pai Rd., Kwai Chung, N.T., Kowloon, Hong Kong Telephone: +852-2421-8611 Facsimile: +852-2480-5479 Email:sales@sih.com.hk http://www.sih.com.hk

Seiko Instruments (H.K.) Ltd. - Shenzhen Rep. Office Room 2212-15, Office Tower, Shun Hing Square Di Wang Commercial Centre, 5002 Shen Nan Dong Road, Shenzhen, 518008, China Telephone: +86-755-8246-2680 Facsimile: +86-755-8246-5140

#### Europe

Seiko Instruments GmbH Siemensstrasse 9 D-63263 Neu Isenburg, Germany Telephone: +49-6102-297-0 Facsimile: +49-6102-297-50100 Email:info@seiko-instruments.de http://www.seiko-instruments.de Room 2701-2703, 27th Floor, Shanghai Plaza, 138 Mid Huaihai Rd., Shanghai 200021, China Telephone: +86-21-6375-6611 Facsimile: +86-21-6375-6727

Seiko Instruments (Shanghai) Inc.

Seiko Instruments Taiwan Inc. 12F, No.101, Sec.2, Nanking E. Rd., Taipei 104, Taiwan, R.O.C. Telephone: +886-2-2563-5001 Facsimile: +886-2-2563-5580 Email:public@sii.co.jp http://www.sii.com.tw

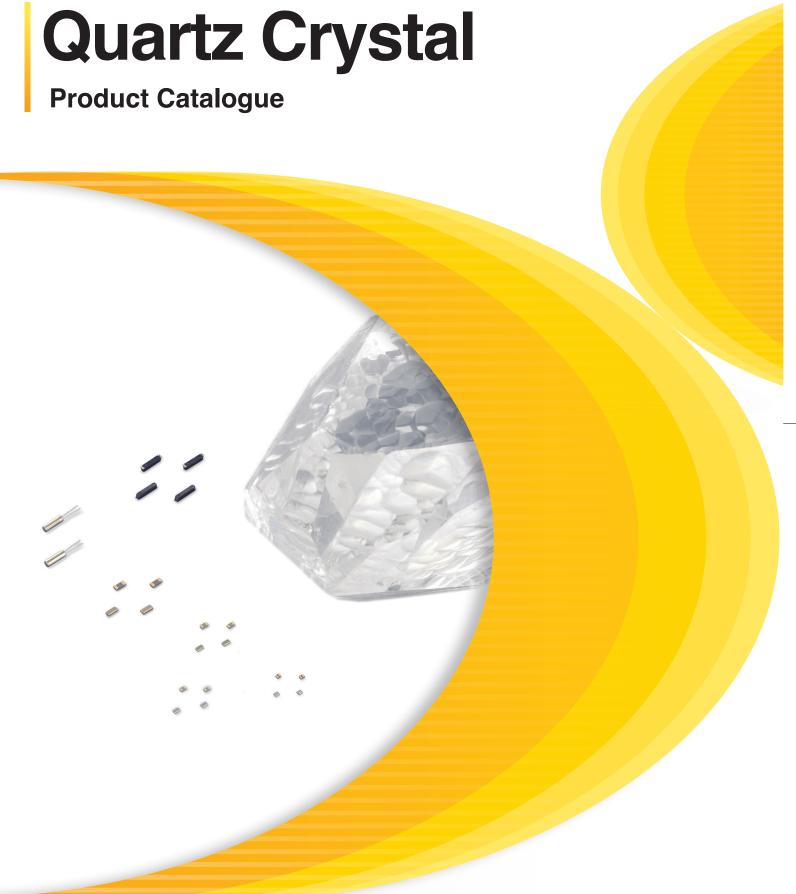
#### North/Central/South America

Seiko Instruments U.S.A., Inc. 21221 S. Western Ave., Suite 250, Torrance, CA 90501, U.S.A. Telephone: +1-310-517-7771 Facsimile: +1-310-517-7792 Email:info@siu-la.com http://www.sii-crystal.com



# SII O





(Specifications are subject to change without notice.)

Released in February 2019

Copyright©2018 Seiko Instruments Inc. All Right Reserved.



Seiko Instruments Inc.



#### Contents

Quartz Crystal Products	6
Ceramic package	
SC-12S	7
SC-16S	8
SC-20S	9
SC-20T	10
SC-20A (For automotive use)	11
SC-32S	12
SC-32A (For automotive use)	13
SC-32P (R1=50kΩ max.) Low ESR Series	14

SSP-T7-F	1
SSP-T7-FL (SMD type low CL resonator for low-power	
microcontrollers)	1

#### Cylinder

VT-200-F	7
VT-200-FL(Cylinder type low CL resonator for low-power	
microcontrollers)18	3
VT-150-F	9
VT-120-F	5
VTC-120-F	1
Oscillator	
High accuracy Crystal Oscillator 32.768kHz SH-32S 22	2

Environmental Activites	25
Quartz Crystal Unit Handling Precautions	26
Oscillation Circuit Design Precautions	29
Packing	31

# **Creating Time - Optimizing Time - Enriching Time**

Seiko Instruments Inc. (SII), founded in 1937 as a member of the Seiko Group specializing in the manufacture of watches, has leveraged its core competency in high precision watches to create a wide range of new products and technologies.

Over the years SII has developed high-precision processed parts and machine tools that pride themselves on their sub-micron processing capability, quartz crystals that came about as a result of our quartz watch R&D, and electronic components such as micro batteries. Optimizing our extensive experience and expertise, we have since diversified into such new fields as compact, lightweight, exceedingly quiet thermal printers, and inkjet printheads, a key component in wide format inkjet printers for corporate use.

SII, in the years to come, will maintain an uncompromised dedication to its time-honored technologies and innovations of craftsmanship, miniaturization, and efficiency that meet the needs of our changing society and enrich the lives of those around us.

1 lattori	1917 K. Hattori	& Co., Ltd.	1983 Hattori Seiko Co.,	1997 Ltd. Seiko Corpora	tion 2007 Seiko Holdings Corporation
		1947 Wako Co., I	.td.	1993 Today's Seiko Ti	2005 Today's Seiko NPC Corporatio 2001 Seiko Watch Corporation
	1892 Seikosha	197 Seik	0 osha Co., Ltd.	1996 Seiko Clock 1996 Seiko Precis	
		1937 Daini Seikosha Co	1983 Seiko Instrum , Ltd. Electronics Ltd		2013 Seiko Solutions Inc.

4

# PRECISION, **CRAFTSMANSHIP and MINIATURIZATION**

## Leveraging Watch Making Technology

With Precision, we apply our Craftsmanship to provide Miniaturization advantages to customers' product development around the world.



## **Electronic Components and High-performance Materials**

Since 1953

Since 1975

Since 1976

**Precise Timing for** 

**Electronic Devices** 

Small and powerful

Silver Oxide Battery

"SEIZAIKEN"

**Silver Oxide Battery** 

No corrosion, strong,

ultra high elasticity

**Co-Ni alloy product** 

"SPRON"



Excellent heat and corrosion resistance Samarium-cobalt Magnet "DIANET"

**Tuning Fork Quartz** 

**Crystal Resonator** 



Since 1988 Stable and reliable

**Rechargeable Battery** and Capacitor





The sophisticated metal product, "SPRON", was born as a material to be used in a "mainspring", which is a drive source of mechanical watches. "SPRON" has been used for over 50 years as a drive source of watches by utilizing its high elasticity, high strength, and high heat resistance. Evaluated highly for its corrosion resistance and durable quality, "SPRON" is used for key devises in various fields like valves in semiconductor manufacturing equipment and dental treatment devices.

A small-sized primary battery that features a large electrical capacity and almost no voltage drop until the last stage of electrical discharge even though its minimum diameter is 4 mm. Since the birth of quartz watches, we have developed batteries to increase their electrical capacity. We have also pursued better leakage resistance and long term reliability characteristics. It is expected to be used as a power supply for disposable, wearable, IoT, and the low energy Bluetooth products.

Tuning Fork Quartz Crystal Resonators were developed as the basis for accuracy in the Quartz Watch. Our high quality and reliability was prioritized to meet the stringent requirements for watches. Recent demand in IoT developments where devices are required to operate with low power consumption and accurate communication protocol timing have increased the demand for smaller components with the same rugged reliability as is required in watches. For applications which require absolute lowest power consumption, our Timing Crystals are available in our Low CL specifications.

"DIANET", which has its origin in rotor magnets of quartz watches, has superior heat resistance and strong magnetic force even though its outside diameter is only 1 mm or less. The Sendai Unit acquired IATF 16949 Quality Management System for the automotive production industry. "DIANET" is used for a wide range of automotive products, and its advanced quality and performance are highly recognized. In addition, "DIANET" is also used in actuators of cameras for smart phones and medical devices.

The rechargeable batteries supporting a wide temperature range of -40°C to 85°C are available in our lineup. They are suitable for operating very low power consumption devices, for backup power supply of clock and memory functions of a wide range of products. The capacitor will correspond to the new needs of energy harvesting devices. Capacitors are extremely useful in various applications.

# Quartz Crystal Products

With Precision, we apply our Craftsmanship to provide Miniaturization advantages to customers' developed products around the world.

#### **Features**

- Mirror finishing wafer processing technology
- Largest Quartz wafer in the industry
- Manufacturing capacity for expanded wafer processing • Extensive experience and manufacturing knowledge for Quartz tuning fork crystals

Line up		Size (mm)	Frequency Tolerance (ppm) (*)	Parabolic Coefficient (10 <sup>-6/o</sup> C <sup>2</sup> )	Load Capacitance (pF)	Motional Resistance (kΩ)	Operating Temp. (°C)	Storage Temp. (°C)	Remarks
SC-32S		3.2×1.5×0.85	±20	(-0.030±10%)	6, 7, 9, 12.5	70	-40 to +85	-55 to +125	
SC-32P		3.2×1.5×0.85	±20	(-0.033±10%)	6, 7, 9, 12.5	50	-40 to +85	-55 to +125	Low ESR type
SC-32A		3.2×1.5×0.85	±20	(-0.030±10%)	6, 7, 9, 12.5	70	-55 to +125	-55 to +125	For automotive use
SC-20S	4	2.0×1.2×0.60	±20	(-0.030±10%)	6, 7, 9, 12.5	70	-40 to +85	-55 to +125	
SC-20T		2.0×1.2×0.35	±20	(-0.033±10%)	6, 7, 9, 12.5	75	-40 to +85	-55 to +125	Low height 2 terminals / 4 terminals
SC-20A	9	2.0×1.2×0.60	±20	(-0.030±10%)	6, 7, 9, 12.5	90	-55 to +125	-55 to +125	For automotive use
SC-16S	4 4 4 4	1.6×1.0×0.50	±20	(-0.036±10%)	6, 7, 9, 12.5	90	-40 to +85	-55 to +125	
SC-12S	4 °	1.2×1.0×0.50	±20	(-0.036±10%)	6, 7, 9, 12.5	90	-40 to +85	-55 to +125	2 terminals / 4 terminals

\* Please contact us and specify your requirements.



#### Cylinder type Quartz Crystal Resonator



#### SMD type Crystal Oscillator (Ceramic package)

Line up	Size (mm)	Frequency tolerance (ppm)	Frequency temperature coefficient –40 to +85°C (ppm)	Current consumption Typ. (µA)	Supply voltage (V)	Temperature Compensated voltage (V)	Operating Temp. (°C)
SH-32S	 3.2×1.5×0.9	±3	±50	1.0	1.3 to 5.5	2.0 to 5.5	-40 to +85

Application Wireless DSC Smart phone Note PC Health care Car navigatio Smart mete Surveillance Wearable communication module device camera device

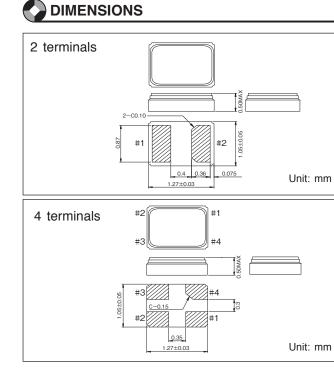
# Ceramic package

#### **SC-12S**



#### STANDARD SPECIFICATIONS

STANDARD SPECIFI	CATIONS		ditions where not	specified (Temperature: 25±2°C, DL: 0.1µW)
			cations	
Item	Symbol	2 terminals 4 terminals		Conditions / Notes
Nominal Frequency	f_nom	32.768kHz		
Frequency Tolerance	f_tol	±20>	<10 <sup>-6</sup>	* Please contact us about available tolerance.
Turnover Temperature	Ti	+25±5°C		
Parabolic Coefficient	В	(-0.036±10%) ×10 <sup>-6</sup> /°C <sup>2</sup>		
Load Capacitance	CL	6.0pF, 7.0pF, 9.0pF, 12.5pF		* Please contact us about available CL.
Motional Resistance (ESR)	R <sub>1</sub>	90kΩ	max.	
Absolute Maximum Drive Level	DLmax.	0.3µW	/ max.	
Level of Drive	DL	0.1µV	V typ.	
Shunt Capacitance	Co	1.4pF typ.		
Frequency Ageing	f_age	±5×10 <sup>-6</sup>		+25±3°C, First Year
Operating Temperature	T_use	-40°C t	o +85°C	
Storage Temperature	T_stg	–55°C to	) +125°C	Storage as single product



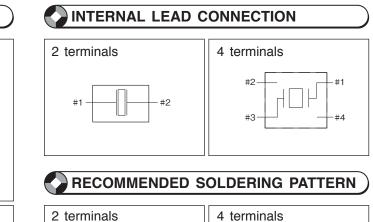
Remark Please make sure there is no pattern under SC-12S on the circuit board.

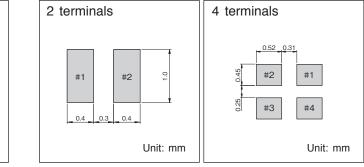
#### **FEATURES**

- Ultra small size package  $(1.2 \times 1.0 \times 0.5 \text{mm max.})$ .
- · SMD type suitable for high density surface mounting.
- · Excellent shock and heat resistance.
- · Pb-free.
- · Complies with EU RoHS directive.
- Built-in crystal resonator processed by high reliable photo-lithographic technology.

#### 

Mobile Phone, Wearable, Module, Sub-clock function for a variety of Microcontroller, etc.





Ceramic package

#### **SC-16S**



#### FEATURES

- · SMD type suitable for high density surface mounting.
- Thin type with height 0.5mm max.
- · Excellent shock and heat resistance.
- · Pb-free.
- · Complies with EU RoHS directive.
- · Built-in crystal resonator processed by high reliable photo-lithographic technology.

#### APPLICATIONS

Mobile Phone, Wearable, Module, Sub-clock function for a variety of Microcontroller, etc.

#### STANDARD SPECIFICATIONS

#### Conditions where not specified (Temperature: 25±2°C, DL: 0.1µW)

Item	Symbol	Specifications	Conditions / Notes
Nominal Frequency	f_nom	32.768kHz	
Frequency Tolerance	f_tol	±20×10 <sup>-6</sup>	* Please contact us about available tolerance.
Turnover Temperature	Ti	+25±5°C	
Parabolic Coefficient	В	(-0.036±10%)×10 <sup>-6</sup> /°C <sup>2</sup>	
Load Capacitance	CL	6.0pF, 7.0pF, 9.0pF, 12.5pF	* Please contact us about available CL.
Motional Resistance (ESR)	R <sub>1</sub>	90kΩ max.	
Absolute Maximum Drive Level	olute Maximum Drive Level DLmax. 0.5µW max.		
Level of Drive	DL	0.1µW typ.	
Shunt Capacitance	C <sub>0</sub>	1.2pF typ.	
Frequency Ageing	f_age	±3×10 <sup>-6</sup>	+25±3°C, First Year
Operating Temperature	T_use	-40°C to +85°C	
Storage Temperature	T_stg	–55°C to +125°C	Storage as single product

# Ceramic package

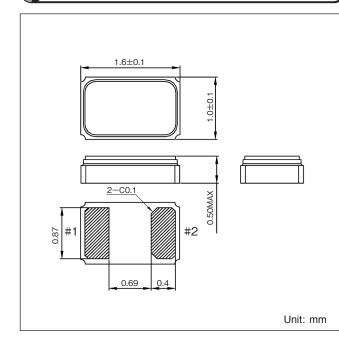
#### **SC-20S**

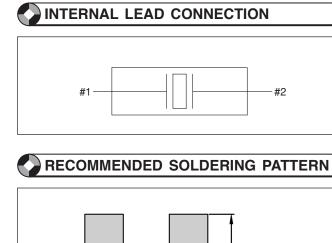


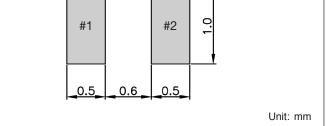
#### STANDARD SPECIFICATIONS

STANDARD SPECIFICATIONS							
Conditions where not specified (Temperature: 25±2°C,							
Item	Symbol	Specifications	Conditions / Notes				
Nominal Frequency	f_nom	32.768kHz					
Frequency Tolerance	f_tol	±5×10 <sup>-6</sup> , ±10×10 <sup>-6</sup> , ±20×10 <sup>-6</sup>	* Please contact us about available tolerance.				
Turnover Temperature	Ti	+25±5°C					
Parabolic Coefficient	В	(-0.030±10%)×10 <sup>-6</sup> /°C <sup>2</sup>					
Load Capacitance	CL	6.0pF, 7.0pF, 9.0pF, 12.5pF	* Please contact us about available CL.				
Motional Resistance (ESR)	R <sub>1</sub>	70kΩ max.					
Absolute Maximum Drive Level	DLmax.	1.0µW max.					
Level of Drive	DL	0.1µW typ.					
Shunt Capacitance	C <sub>0</sub>	1.3pF typ.					
Frequency Ageing	f_age	±3×10 <sup>-6</sup>	+25±3°C, First Year				
Operating Temperature	T_use	-40°C to +85°C					
Storage Temperature	T_stg	–55°C to +125°C	Storage as single product				

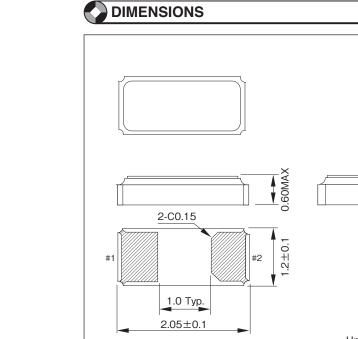
#### 







Remark Please make sure there is no pattern under SC-16S on the circuit board.



Unit: mm

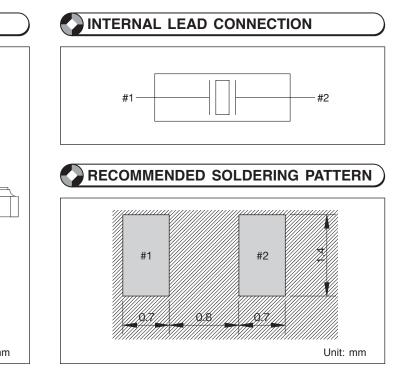
Remark Please make sure there is no pattern under SC-20S on the circuit board.

#### **FEATURES**

- Thin type with height 0.6mm max.
- · SMD type suitable for high density surface mounting.
- · Excellent shock and heat resistance.
- Pb-free.
- · Complies with EU RoHS directive.
- · Built-in crystal resonator processed by high reliable photo-lithographic technology.

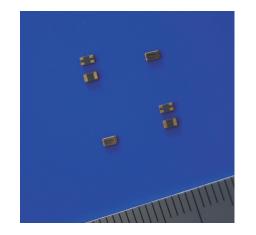
#### 

Mobile Phone, Wearable, Module, Sub-clock function for a variety of Microcontroller, etc.



Ceramic package

#### **SC-20T**



#### FEATURES

- Ultra thin type with height 0.35mm max.
- SMD type suitable for high density surface mounting.
- Excellent shock and heat resistance.
- Excellent si
  Pb-free.
- Complies with EU RoHS directive.
- Built-in crystal resonator processed by high reliable photo-lithographic technology.

#### APPLICATIONS

Smart card, Wearable, Module, Sub-clock function for a variety of Microcontroller, etc.

#### STANDARD SPECIFICATIONS

Conditions where not specified (Temperature: 25±2°C, DL: 0.1 $\mu$ W)

Item	Symbol	Specifi	cations	Conditions / Notes
item	Symbol	2 terminals	4 terminals	Conditions / Notes
Nominal Frequency	f_nom	32.768kHz		
Frequency Tolerance	f_tol	±20>	×10 <sup>-6</sup>	* Please contact us about available tolerance.
Turnover Temperature	Ti	+25±5°C		
Parabolic Coefficient	В	(-0.033±10%)×10 <sup>-6</sup> /°C <sup>2</sup>		
Load Capacitance	CL	6.0pF, 7.0pF, 9.0pF, 12.5pF		* Please contact us about available CL.
Motional Resistance (ESR)	R <sub>1</sub>	75kΩ	max.	
Absolute Maximum Drive Level	DLmax.	1.0µW	/ max.	
Level of Drive	DL	0.1µV	V typ.	
Shunt Capacitance	C <sub>0</sub>	1.0pF typ. 0.8pF typ.		
Frequency Ageing	f_age	±3×10 <sup>-6</sup>		+25±3°C, First Year
Operating Temperature	T_use	-40°C te	o +85°C	
Storage Temperature	T_stg	–55°C to	) +125°C	Storage as single product

## Ceramic package

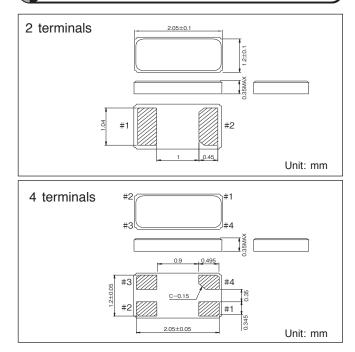
## SC-20A (For automotive use)



#### STANDARD SPECIFICATIONS

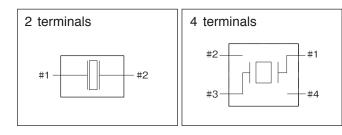
Item	Symbol	Specifications	Conditions / Notes
		•	Conditions / Notes
Nominal Frequency	f_nom	32.768kHz	
Frequency Tolerance	f_tol	±20×10 <sup>-6</sup>	* Please contact us about available tolerance.
Turnover Temperature	Ti	+25±5°C	
Parabolic Coefficient	В	(-0.030±10%)×10 <sup>-6</sup> /°C <sup>2</sup>	
Load Capacitance	CL	6.0pF, 7.0pF, 9.0pF, 12.5pF	* Please contact us about available CL.
Motional Resistance (ESR)	R <sub>1</sub>	90kΩ max.	
Absolute Maximum Drive Level	DLmax.	1.0µW max.	
Level of Drive	DL	0.1µW typ.	
Shunt Capacitance	C <sub>0</sub>	1.3pF typ.	
Frequency Ageing	f_age	±3×10 <sup>-6</sup>	+25±3°C, First Year
Operating Temperature	T_use	–55°C to +125°C	
Storage Temperature	T_stg	–55°C to +125°C	Storage as single product

#### 

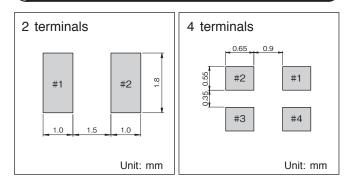


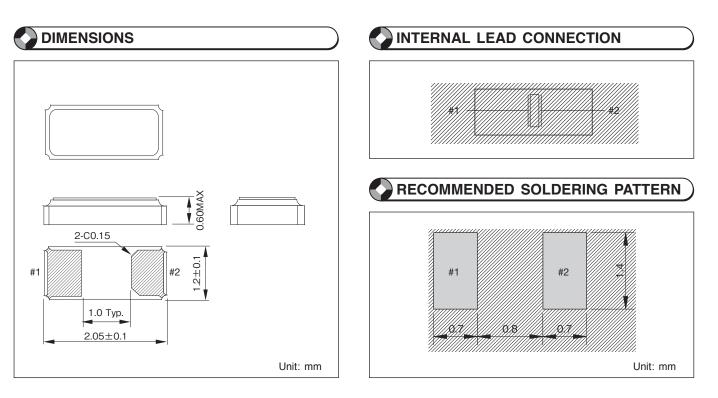
Remark Please make sure there is no pattern under SC-20T on the circuit board.

## INTERNAL LEAD CONNECTION



#### RECOMMENDED SOLDERING PATTERN





Remark Please make sure there is no pattern under SC-20A on the circuit board.

10

## )

#### **FEATURES**

- · Conforms to "AEC-Q200".
- Thin type with height 0.6mm max.
- · SMD type suitable for high density surface mounting.
- · Excellent shock and heat resistance.
- · Pb-free.
- · Complies with EU RoHS directive.
- Built-in crystal resonator processed by high reliable photo-lithographic technology.

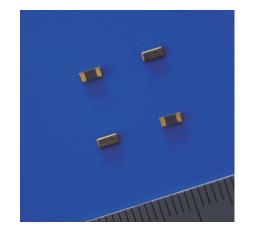
#### **APPLICATIONS**

Car Audio, Car Navigation, ECU sub-clock, In-vehicle clock etc.

Conditions where not specified (Temperature: 25±2°C, DL: 0.1 $\mu W)$ 

Ceramic package

#### **SC-32S**



#### FEATURES

- Thin type with height 0.85mm max.
- · SMD type suitable for high density surface mounting.
- Excellent shock and heat resistance.
- · Pb-free.
- · Complies with EU RoHS directive.
- · Built-in crystal resonator processed by high reliable photo-lithographic technology.

#### APPLICATIONS

Mobile Phone, Wearable, Module, Sub-clock function for a variety of Microcontroller, etc.

#### STANDARD SPECIFICATIONS

#### Conditions where not specified (Temperature: 25±2°C, DL: 0.1µW)

Item	Symbol	Specif	cations	Conditions / Notes
Nominal Frequency	f_nom	32.768kHz	38.4kHz	
Frequency Tolerance	f_tol	±5×10 <sup>-6</sup> , ±10>	10 <sup>-6</sup> , ±20×10 <sup>-6</sup>	* Please contact us about available tolerance.
Turnover Temperature	Ti	+25	±5°C	
Parabolic Coefficient	В	(-0.030±10	%)×10 <sup>-6</sup> /°C <sup>2</sup>	
Load Capacitance	CL	6.0pF, 7.0pF,	9.0pF, 12.5pF	* Please contact us about available CL.
Motional Resistance (ESR)	R <sub>1</sub>	70kΩ	2 max.	
Absolute Maximum Drive Level	DLmax.	1.0µV	V max.	
Level of Drive	DL	0.1µ'	W typ.	
Shunt Capacitance	C <sub>0</sub>	1.0p	F typ.	
Frequency Ageing	f_age	±3×10 <sup>-6</sup>		+25±3°C, First Year
Operating Temperature	T_use	-40°C to +85°C		
Storage Temperature	T_stg	–55°C to	o +125°C	Storage as single product

## Ceramic package

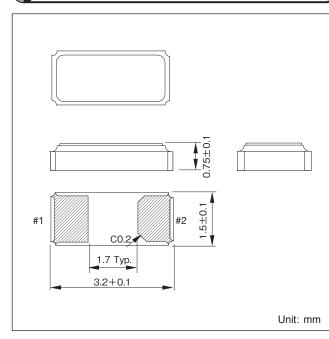
## SC-32A (For automotive use)



#### STANDARD SPECIFICATIONS

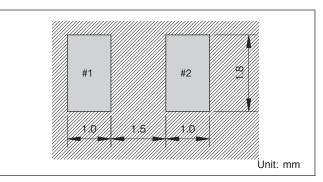
Conditions where not specified (Temperature: 25±2°C,						
Item	Symbol	Specifications	Conditions / Notes			
Nominal Frequency	f_nom	32.768kHz				
Frequency Tolerance	f_tol	±20×10 <sup>-6</sup>	* Please contact us about available tolerance.			
Turnover Temperature	Ti	+25±5°C				
Parabolic Coefficient	В	(-0.030±10%)×10 <sup>-6</sup> /°C <sup>2</sup>				
Load Capacitance	CL	6.0pF, 7.0pF, 9.0pF, 12.5pF	* Please contact us about available CL.			
Motional Resistance (ESR)	R <sub>1</sub>	70kΩ max.				
Absolute Maximum Drive Level	DLmax.	1.0µW max.				
Level of Drive	DL	0.1µW typ.				
Shunt Capacitance	C <sub>0</sub>	1.0pF typ.				
Frequency Ageing	f_age	±3×10 <sup>-6</sup>	+25±3°C, First Year			
Operating Temperature	T_use	–55°C to +125°C				
Storage Temperature	T_stg	–55°C to +125°C	Storage as single product			

#### 

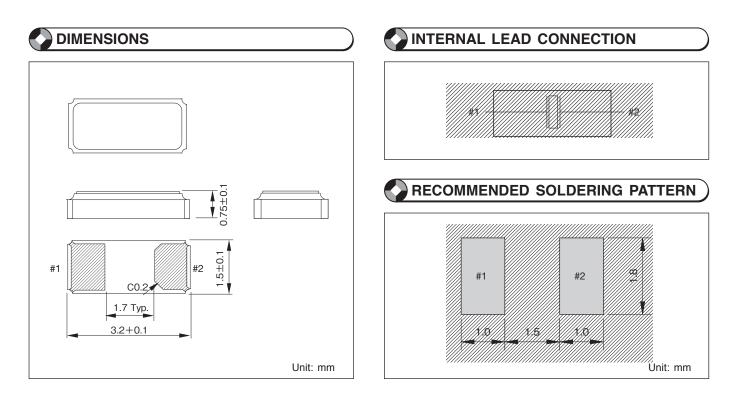


# INTERNAL LEAD CONNECTION

#### RECOMMENDED SOLDERING PATTERN







Remark Please make sure there is no pattern under SC-32A on the circuit board.

#### FEATURES

- · Conforms to "AEC-Q200".
- · SMD type suitable for high density surface mounting.
- · Excellent shock and heat resistance.
- · Pb-free.
- · Complies with EU RoHS directive.
- · Built-in crystal resonator processed by high reliable photo-lithographic technology.

#### APPLICATIONS

Car Audio, Car Navigation, ECU sub-clock, In-vehicle clock etc.

### SC-32P (R1=50kΩ max.) Low ESR Series

Symbol

f\_nom

f\_tol

Ti

B C<sub>L</sub>

R<sub>1</sub>

DLmax.

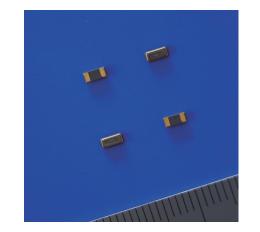
DL

 $C_0$ 

f\_age

T\_use

T\_stg



STANDARD SPECIFICATIONS

Item

Nominal Frequency

Frequency Tolerance

Parabolic Coefficient

Load Capacitance

Level of Drive

Shunt Capacitance

**Frequency Ageing** 

Operating Temperature Storage Temperature

Turnover Temperature

Motional Resistance (ESR)

Absolute Maximum Drive Level

#### **FEATURES**

- Suitable for Microcontroller with Low ESR (R1=50kΩ max.).
- · SMD type suitable for high density surface mounting.
- · Excellent shock and heat resistance.
- · Pb-free.

Specifications

32.768kHz

±5×10<sup>-6</sup>, ±10×10<sup>-6</sup>, ±20×10<sup>-6</sup>

+25±5°C

(-0.033±10%)×10<sup>-6</sup>/°C<sup>2</sup>

6.0pF, 7.0pF, 9.0pF, 12.5pF

50kΩ max.

1.0µW max.

0.1µW typ.

1.0pF typ.

±3×10<sup>-6</sup>

-40°C to +85°C

-55°C to +125°C

- · Complies with EU RoHS directive.
- Built-in crystal resonator processed by high reliable photo-lithographic technology.

Conditions where not specified (Temperature:  $25\pm2^{\circ}C$ , DL:  $0.1\mu W$ )

**Conditions / Notes** 

Please contact us about available tolerance

Please contact us about available CL.

#### 

PC, Tablet, BLE Module, Wearable

# Plastic mold

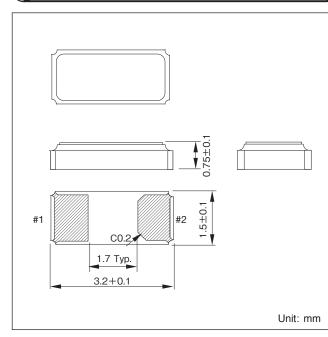
#### SSP-T7-F



#### STANDARD SPECIFICATIONS

Item	Symbol Specifications		Conditions / Notes
Nominal Frequency	f_nom	32.768kHz	
Frequency Tolerance	f_tol	$\pm 5 \times 10^{-6}, \pm 10 \times 10^{-6}, \pm 20 \times 10^{-6}$	* Please contact us about available tolerance.
Turnover Temperature	Ti	+25±5°C	
Parabolic Coefficient	В	(-0.033±10%)×10 <sup>-6</sup> /°C <sup>2</sup>	
Load Capacitance	CL	7.0pF, 9.0pF, 12.5pF	* Please contact us about available CL.
Motional Resistance (ESR)	R <sub>1</sub>	65kΩ max.	
Absolute Maximum Drive Level	DLmax.	1.0µW max.	
Level of Drive	DL	0.1µW typ.	
Shunt Capacitance	Co	0.9pF typ.	
Frequency Ageing	f_age	±3×10 <sup>-6</sup>	+25±3°C, First Year
Operating Temperature	T_use	-40°C to +85°C	
Storage Temperature	T_stg	–55°C to +125°C	Storage as single product

#### 

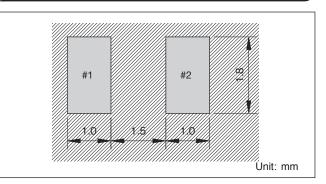


INTERNAL LEAD CONNECTION

+25±3°C, First Year

Storage as single product

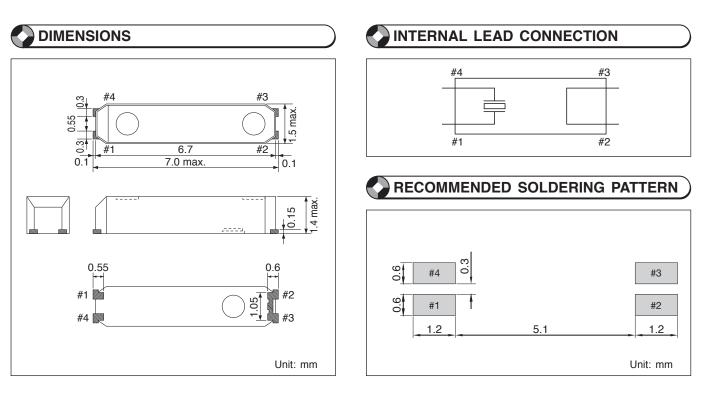
#### RECOMMENDED SOLDERING PATTERN



Remark Please make sure there is no pattern under SC-32P on the circuit board.



Seiko Instruments Inc.



Remark Please make sure there is no pattern under SSP-T7-F on the circuit board.

#### FEATURES

- Thin type with height 1.4mm max.
- · SMD type suitable for high density surface mounting.
- · Excellent shock and heat resistance.
- Complies with EU RoHS directive.
- Complete Halogen-free.
- · Pb-free.
- Built-in crystal resonator processed by high reliable photo-lithographic technology.

#### 

Mobile Phone, Wearable, Module, Sub-clock function for a variety of Microcontroller, etc.

## SSP-T7-FL (SMD type low CL resonator for low-power microcontrollers)



#### FEATURES

- Consumes one tenth the standby power of general crystal resonators (with a load capacitance of 12.5 pF) (\*1).
- · Excellent low drive characteristics.
- · Complies with EU RoHS directive.
- Complete Halogen-free, Pb-free.
- Built-in crystal resonator processed by high reliable photo-lithographic technology.
- (\*1) When using a microcontroller that supports low CL.

#### 

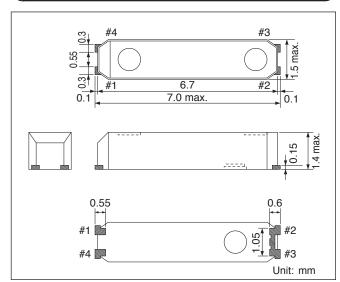
- Consumer electronics products for saving standby energy consumption.
- The devices which is operated by the battery requiring a long battery life.

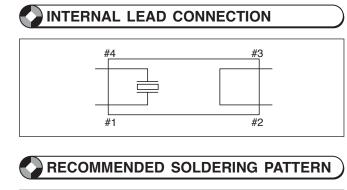
#### STANDARD SPECIFICATIONS

Conditions where not specified (Temperature: 25±2°C, DL: 0.01µW)

Item	Symbol	Specifications	Conditions / Notes
Nominal Frequency	f_nom	32.768kHz	
Frequency Tolerance	f_tol	±±5×10 <sup>-6</sup> , ±10×10 <sup>-6</sup> , ±20×10 <sup>-6</sup>	* Please contact us about available tolerance.
Turnover Temperature	Ti	+25±5°C	
Parabolic Coefficient	В	(-0.033±10%)×10 <sup>-6</sup> /°C <sup>2</sup>	
Load Capacitance	CL	3.7pF, 4.4pF, 6.0pF	* Please contact us about available CL.
Motional Resistance (ESR)	R <sub>1</sub>	65kΩ max.	
Absolute Maximum Drive Level	DLmax.	1.0μW max.	
Level of Drive	DL	0.01µW typ.	
Shunt Capacitance	C <sub>0</sub>	0.9pF typ.	
Frequency Ageing	f_age	±3×10 <sup>-6</sup>	+25±3°C, First Year
Operating Temperature	T_use	–40°C to +85°C	
Storage Temperature	T_stg	–55°C to +125°C	Storage as single product

#### DIMENSIONS





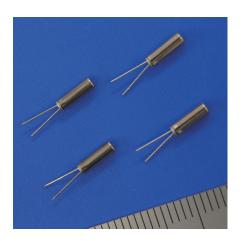


Remark Please make sure there is no pattern under SSP-T7-FL on the circuit board.

#### CAUTION

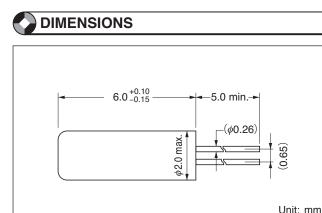
The SSP-T7-FL is designed for use in ultra-low-power microcontrollers. Do not use this resonator in regular microcontrollers as it might cause problems with oscillation.

#### VT-200-F



#### STANDARD SPECIFICATIONS

Item	Symbol	Specifications	Conditions / Notes
Nominal Frequency	f_nom	32.768kHz	
Frequency Tolerance	f_tol	±5×10 <sup>-6</sup> , ±10×10 <sup>-6</sup> , ±20×10 <sup>-6</sup>	* Please contact us about available tolerance.
Turnover Temperature	Ti	+25±5°C	
Parabolic Coefficient	В	(-0.035±10%)×10 <sup>-6</sup> /°C <sup>2</sup>	
Load Capacitance	CL	7.0pF, 9.0pF, 12.5pF	* Please contact us about available CL.
Motional Resistance (ESR)	R <sub>1</sub>	50kΩ max.	
Absolute Maximum Drive Level	DLmax.	1.0μW max.	
Level of Drive	DL	0.1µW typ.	
Shunt Capacitance	Co	0.9pF typ.	
Frequency Ageing	f_age	±3×10 <sup>-6</sup>	+25±3°C, First Year
Operating Temperature	T_use	–40°C to +85°C	
Storage Temperature	T_stg	–40°C to +85°C	Storage as single product



Remark Please make sure there is no pattern under VT-200-F on the circuit board.

#### FEATURES

- 2.0Φ tubular package.
- Built-in crystal resonator processed by high reliable photo-lithographic technology.
- Excellent shock resistance and environmental characteristics.
- Pb-free.
- · Complies with EU RoHS directive.

#### 

Clocks, Timers, Water/Electricity Meters,

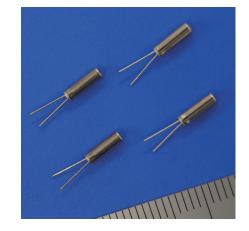
Remote controllers,

Sub-clock function for a variety of Microcontroller, etc.

Conditions where not specified (Temperature:  $25\pm2^{\circ}C$ , DL:  $0.1\mu$ W)

Cylinder

#### VT-200-FL (Cylinder type low CL resonator for low-power microcontrollers)



#### STANDARD SPECIFICATIONS

#### FEATURES

- · Consumes one tenth the standby power of general crystal resonators (with a load capacitance of 12.5 pF) (\*1).
- · Built-in crystal resonator processed by high reliable photo-lithographic technology.
- · Excellent low drive characteristics.
- · Pb-free.
- · Complies with EU RoHS directive.
- (\*1) When using a microcontroller that supports low CL.

#### APPLICATIONS

- · Consumer-electronics products for saving standby energy consumption.
- · The devices which is operated by the battery requiring a long battery life.
- Conditions where not specified (Temperature: 25±2°C, DL: 0.01µW)

Item	Symbol	Specifications	Conditions / Notes
Nominal Frequency	f_nom	32.768kHz	
Frequency Tolerance	f_tol	$\pm 5 \times 10^{-6}, \pm 10 \times 10^{-6}, \pm 20 \times 10^{-6}$	* Please contact us about available tolerance.
Turnover Temperature	Ti	+25±5°C	
Parabolic Coefficient	В	(-0.035±10%)×10 <sup>-6</sup> /°C <sup>2</sup>	
Load Capacitance	CL	3.7pF, 4.4pF, 6.0pF	* Please contact us about available CL.
Motional Resistance (ESR)	R <sub>1</sub>	50kΩ max.	
Absolute Maximum Drive Level	DLmax.	1.0µW max.	
Level of Drive	DL	0.01µW typ.	
Shunt Capacitance	C <sub>0</sub>	0.9pF typ.	
Frequency Ageing	f_age	±3×10 <sup>-6</sup>	+25±3°C, First Year
Operating Temperature	T_use	-40°C to +85°C	
Storage Temperature	T_stg	–40°C to +85°C	Storage as single product

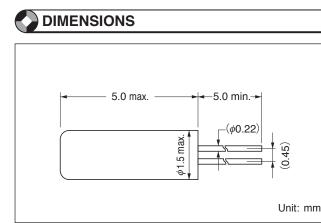


#### **VT-150-F**

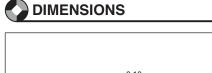


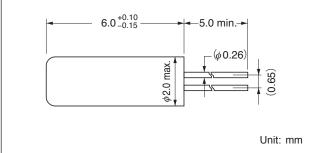
#### STANDARD SPECIFICATIONS

Item	Symbol	Specifications	Conditions / Notes
Nominal Frequency	f_nom	32.768kHz	
Frequency Tolerance	f_tol	±5×10 <sup>-6</sup> , ±10×10 <sup>-6</sup> , ±20×10 <sup>-6</sup>	* Please contact us about available tolerance.
Turnover Temperature	Ti	+25±5°C	
Parabolic Coefficient	В	(-0.035±10%)×10 <sup>-6</sup> /°C <sup>2</sup>	
Load Capacitance	CL	6.0pF, 7.0pF, 9.0pF, 12.5pF	* Please contact us about available CL.
Motional Resistance (ESR)	R <sub>1</sub>	50kΩ max.	
Absolute Maximum Drive Level	DLmax.	1.0μW max.	
Level of Drive	DL	0.1µW typ.	
Shunt Capacitance	C <sub>0</sub>	0.9pF typ.	
Frequency Ageing	f_age	±3×10 <sup>-6</sup>	+25±3°C, First Year
Operating Temperature	T_use	-10°C to +60°C	
Storage Temperature	T_stg	–30°C to +70°C	Storage as single product



#### Remark Please make sure there is no pattern under VT-150-F on the circuit board.





Remark Please make sure there is no pattern under VT-200-FL on the circuit board.

#### CAUTION

The VT-200-FL is designed for use in ultra-low-power microcontrollers. Do not use this resonator in regular microcontrollers as it might cause problems with oscillation.

#### FEATURES

- 1.5Φ tubular package.
- · Built-in crystal resonator processed by high reliable photolithographic technology.
- · Excellent shock resistance and environmental characteristics.
- · Complies with EU RoHS directive.
- Pb-free.

#### APPLICATIONS

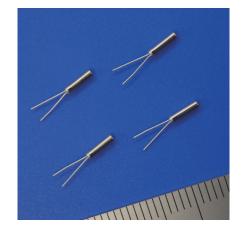
Clocks, Timers, Water/Electricity Meter,

Remote controllers, Sub-clock function for a variety of Microcontroller, etc.

Conditions where not specified (Temperature: 25±2°C, DL: 0.1µW)

Cylinder

### VT-120-F



#### FEATURES

- 1.2Φ tubular package.
- Built-in crystal resonator processed by high reliable photolithographic technology.
- · Excellent shock resistance and environmental characteristics.
- · Complies with EU RoHS directive.
- · Pb-free.

#### APPLICATIONS

Small/Thin Watches. Sub-clock function for a variety of Microcontroller etc.

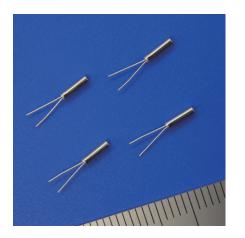
### STANDARD SPECIFICATIONS

Conditions	where	not	specified	(Temperature:	25+2°C	DI: 0.1uW)	
Contaitionio			opoomoa	( iomporataro.	L012 0,	DE: 0.1 p.1.	

Item	Symbol	Specifications	Conditions / Notes
Nominal Frequency	f_nom	32.768kHz	
Frequency Tolerance	f_tol	$\pm 5 \times 10^{-6}, \pm 10 \times 10^{-6}, \pm 20 \times 10^{-6}$	* Please contact us about available tolerance.
Turnover Temperature	Ti	+25±5°C	
Parabolic Coefficient	В	(-0.035±10%)×10 <sup>-6</sup> /°C <sup>2</sup>	
Load Capacitance	CL	6.0pF, 7.0pF, 9.0pF, 12.5pF	* Please contact us about available CL.
Motional Resistance (ESR)	R <sub>1</sub>	50kΩ max.	
Absolute Maximum Drive Level	DLmax.	1.0µW max.	
Level of Drive	DL	0.1µW typ.	
Shunt Capacitance	C <sub>0</sub>	0.8pF typ.	
Frequency Ageing	f_age	±3×10 <sup>-6</sup>	+25±3°C, First Year
Operating Temperature	T_use	-20°C to +60°C	
Storage Temperature	T_stg	-30°C to +70°C	Storage as single product

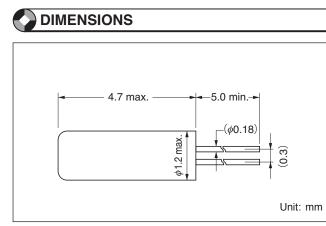


#### VTC-120-F

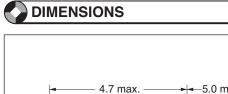


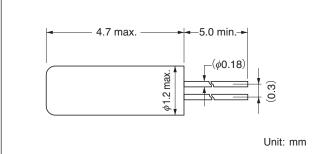
#### STANDARD SPECIFICATIONS

	Conditions where not specified (Temperature: 25±2°C, DL: 0.1µW)						
Item	Symbol		Specification	3	Conditions / Notes		
Nominal Frequency	f_nom	40.0034kHz	60.0035kHz	77.5036kHz			
Frequency Tolerance	f_tol		±20×10 <sup>-6</sup>		* Please contact us about available tolerance.		
Turnover Temperature	Ti	+23±5°C	+22	±5°C			
Parabolic Coefficient	В	(-0.0	035±10%)×10⁻	<sup>6</sup> /°C <sup>2</sup>			
Load Capacitance	CL		10.0pF		* Please contact us about available CL.		
Motional Resistance (ESR)	R <sub>1</sub>	65kΩ max.	50kΩ	max.			
Absolute Maximum Drive Level	DLmax.		1.0µW max.				
Level of Drive	DL		0.1µW typ.				
Shunt Capacitance	C <sub>0</sub>	0.80pF typ.	0.75pF typ.	0.70pF typ.			
Frequency Ageing	f_age	±3×10 <sup>-6</sup>			+25±3°C, First Year		
Operating Temperature	T_use	-	-20°C to +60°0	)			
Storage Temperature	T_stg	-	-30°C to +70°0	)	Storage as single product		



Remark Please make sure there is no pattern under VTC-120-F on the circuit board.





Remark Please make sure there is no pattern under VT-120-F on the circuit board.

#### FEATURES

- 1.20 tubular package.
- Built-in crystal resonator processed by high reliable photolithographic technology.
- Excellent shock resistance and environmental characteristics.
- · Complies with EU RoHS directive.
- Pb-free.

#### APPLICATIONS

Radio-controlled clock

Oscillator

## High Accuracy Crystal Oscillator 32.768kHz SH-32S



#### FEATURES

- · Excellent frequency accuracy and Temperature characteristics
- Low current consumption
- Pb-free
- · Incorporated highly reliable photolithographic crystal resonator

#### APPLICATIONS

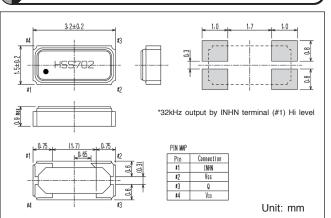
Smart Meter, IoT, Wearable device, Industry device, High precision timing device, Event data recorder

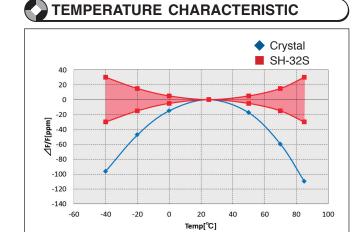
#### STANDARD SPECIFICATIONS

It	Item		Specifications	Unit	Conditions / Notes
Nominal Frequency		f_nom	32.768	kHz	
Voltage Supply Temperature Compensated		V <sub>DD</sub>	1.3 to 5.5	V	(*1)
		V <sub>TEM</sub>	2.0 to 5.5	V	
Temperature	Storage	T_stg	-55 to +125	°C	
range	Operating	T_use	-40 to +85	°C	
Frequency Tol	lerance	f_tol	±3	×10 <sup>-6</sup>	+25°C, V <sub>DD</sub> =3.3V
Temperature r	ange	f0-Tc	±50	×10 <sup>-6</sup>	-40 to +85°C (+25°C is reference)
Frequency / v	oltage coefficient	$f0_V_{DD}$	±1	×10 <sup>-6</sup> /V	
Current concu	motion	I	1.0 Тур.	μA	V
Current consu	Implion	IDD	2.0 Max.	μA	V <sub>DD</sub> =3.3V, No load condition
Symmetry		SYM	50±10	%	Load : 15pF
Rise time / Fa	II time	tr/tf	50 Max.	ns	Load : 15pF, output level 20 to 80%
Innut valtage		V <sub>IL</sub>	0.2V <sub>DD</sub> Max.	V	INHN terminal
Input voltage		VIH	0.8V <sub>DD</sub> Min.	V	INHN terminal
Output valtag		V <sub>OL</sub>	0.4 Max.	V	loL=0.4mA, V <sub>DD</sub> =2.0V
Output voltage		V <sub>OH</sub>	V <sub>DD</sub> -0.4 Min.	V	IoH=-0.4mA, V <sub>DD</sub> =2.0V
Output load condition (CMOS)		CLOUT	15 Max.	pF	CMOS Loading
Start-up time		t_str	0.5 Max.	sec	+25°C
Frequency ag	ing	f_aging	±3	×10 <sup>-6</sup>	+25°C, V <sub>DD</sub> =3.3V, First Year

Unless otherwise stated, characteristics (specifications) shown in the above table are based on the rated operating temperature and voltage condition. (\*1) When the supply voltage becomes 2 V or less, the frequency temperature compensation operation is inactivated.

#### DIMENSIONS





# Oscillator

ABSOLUTE MAXIMUM RATING					
Item	Symbol	Condition	Rated	Unit	
Power Supply & Voltage range	V <sub>DD</sub>	Between V <sub>DD</sub> -V <sub>SS</sub>	-0.3 to +6.5	V	
Input Voltage range	Vin	Input terminal (INHN)	-0.3 to V <sub>DD</sub> +0.3	V	
Output Voltage range	Vout	Output terminal (Q)	-0.3 to V <sub>DD</sub> +0.3	V	
Output Power supply	l <sub>out</sub>	Output terminal (Q)	±10	mA	

\* In order to run SH-32S stability, please be mounted Ceramic • Chip Condensor by more than 0.1µF near SH-32S between V<sub>DD</sub>-V<sub>SS.</sub>

	ON					
Item	Symbol	Condition	MIN	ТҮР	MAX	Unit
Power consumption of starting	l <sub>DD</sub>	INHN=V <sub>DD</sub> =3.3V, C <sub>LOUT</sub> =0pF	_	1.0	2.0	μΑ
(Temperature compensation		Ta=-40°C to +85°C	-			
interval in 2sec)		INHN=V <sub>DD</sub> =5.0V, C <sub>LOUT</sub> =0pF	-	1.5	3.0	μΑ
interval in 2sec)		Ta=-40°C to +85°C				
Power consumption of booting	I <sub>BOOT</sub>	INHN=V <sub>DD</sub> =3.3V, C <sub>LOUT</sub> =0pF	-	1.5	2.5	μΑ
Fower consumption of booting		Ta=-40°C to +85°C				
Power consumption of Disable		INHN=V <sub>SS</sub> =0V, C <sub>LOUT</sub> =0pF	_	0.6	1.5	
	I <sub>DIS</sub>	Ta=-40°C to +85°C	-	0.0	1.5	μΑ

\* In order to be short for oscillation starting time (t\_str), It is the power consumption booting when increased the oscillation drive capability. Booting circuit works until 0.5sec (t\_str+0.5s) from the power supply starting to oscillation starting.

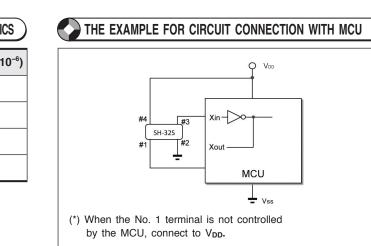
THE FUNCTION FOR INHN TERMINAL				
Input terminal (INHN)	Output terminal (Q)	Oscillation	Notes	
"H" Level	32.768kHz output	Oscillation	-	
"L" Level	Hi-Z	Oscillation	-	
OPEN	-	-	Unavailable	

#### FREQUENCY TORELANCE AND TEMPERATURE CHARACTERISTICS

Temperature range (°C)	Frequency Tolerance (×1
0 to +50	±20
-10 to +60	±30
-20 to +70	±40
-40 to +85	±50

22

Seiko Instruments Inc.



## Check sheet for crystal products selection

When considering our crystal resonator / oscillator, please inform the following items. We will propose applications, characteristics etc. of the usage conditions.

1. Products of interest				
(1) Cylinder type resonator		□VT-200-F	□VT-200-FL	□VT-150-F
		□VT-120-F	□VTC-120-F	
(2) Plastic mold type resonator		□SSP-T7-F	□SSP-T7-FL	
(3) Ceramic package type	e resonator		□SC-32A	□SC-32P
		□SC-32S (38.4kHz)		□SC-20T
(4) Oscillator		□SC-20A □SH-32S	□SC-16S	□SC-12S
		□3⊓-323		
2. Applications				
3. Semiconductors usage	le			
(1) Semiconductors	,-			
	□ASIC		□Others	
□Manufactuer produc	t name			
(2) Purpose of usage				
□Timekeeping	□Stand-by		ation	
□Others				
4. Reguired specification	n for the resonat	tor		
(1) Nominal Frequency (f	_nom)			
□32.768kHz	□Others	kHz		
(2) Operating Temperatur	. ,			
□–40 to +85°C	□Others	°C		
(3) Frequency Tolerance	. , . ,			
□±20ppm		□±5ppm		
Others				
<ul><li>(4) Load Capacitance (C<sub>L</sub></li><li>□12.5pF</li></ul>				
□ 12.5pP		□7pF	□6pF	
(5) Number of terminals (	•	125)		
$\square 2 \text{ terminals}$	$\square$ 4 terminals	,		
5. Required specification				
(1) Frequency-temperature	e coefficient (fo_T	c)		
□±50ppm (-40 to +85	°C) □±40ppm	(-20 to +70°C)		
□±30ppm (-10 to +60	°C) □±20ppm	(0 to +50°C)		
6. Special requirement				
e.g.) Automotive usage	e or medical devi	ce usage or special qu	ality requirement.	
7. Others				

## **Environmental Activites**

## **SII Group Environmental Policy**

#### Environmental Concept

SII Group will continue to harmonize its corporate activities with the global environment, designate the "Three Green" concept consisting of Green Process, Green Products and Green Life as our basic concept, promote and conduct environmental activities, and contribute to the establishment of a sustainable society that can coexist with nature.

## **Environmental Actions taken by Quartz Crystal Division**

#### 1. Provide Environmentally Friendly Products and Services

- · Promote LCA (Life Cycle Assessment)
- Promote lead-free soldering
- · Expand "Green Purchasing' · Expand lineup of SII's green products
- · Scheduled to be Halogen-free

#### 2. Save Energy and Contribute to diminish Global warming

· Energy Saving in Production Process while expanding sales.

#### 3. Maintain zero emissions, and promote resource saving as well as recycling, and the reduction of industrial waste

crystal electrode membrane, plastic mold resin, lead frame, etc. → Promoting resource saving and 3R (Reduce, Re-use, Re-cycle) activities.

#### 4. Encourage Employees to contribute to the Protection of the Environment in their every day life, personal as well as the professional

- · Stop using ozone-layer depleting materials:
- $\rightarrow$  SII discontinued specific fluorine at the end of 1991.
- $\rightarrow$  SII discontinued trichloroethane at the end of 1992.

 $\rightarrow$  SII discontinued mehtylene chloride at the end of 1996.

Establish a green procurement standard, specify materials to be entirely eliminated from products, and promote activities to observe international legal regulations (RoHS and WEEE directives, etc.).

#### 5. Green Life

our site and contributing to local communities by communicating with local residents.

#### 6. Trend of Miniaturizing of SMD Quartz Crystal Unit

Products	SSP-T7-F	SC-32S	SC-16S	SC-12S
Area (mm <sup>2</sup> Max.)	10.5	5.3	1.9	1.43
Height (mmMax.)	1.4	0.85	0.5	0.5
Weight (mg)	28	12	2.8	2.0

24

Promoting measures for more efficient operation of air conditioning equipment, etc. to reduce CO<sub>2</sub> emissions

· Promoting to abolish any toxic or dangerous material, use environment-friendly substitutes and re-use; guartz

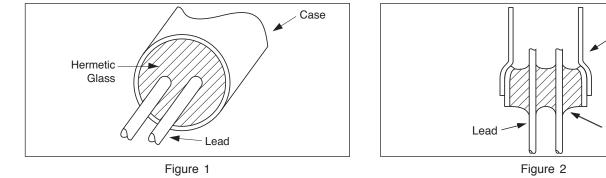
· Our manufacturing site is located close to Ohirasan Natural Park. Accordingly we promote planting trees at

## **Quartz Crystal Unit Handling Precautions**

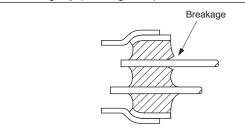
#### 1. MOUNTING PRECAUTIONS Lead Type Crystal Units

#### Structure

Tubular crystal units (VT) are hermetically sealed using glass (see Figures 1 and 2)



- Unbending the lead
  - (1) DO NOT pull the lead excessively if unbending a lead or removing a crystal unit. The excessive force may crack the glass and reduce the degree of vacuum. This may eventually result in deterioration of the characteristics and may also break the crystal chip (see Figure 3).
  - Unbend the lead by pressing on the bent part from both the upper and lower sides with fixing the bottom of lead (2)tightly (see Figure 4).



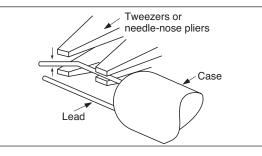


Figure 4

Case

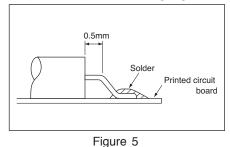
Glass

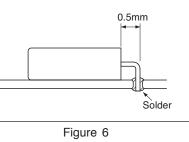
Figure 3

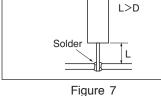
Bending the lead

break the crystal chip

- (1) Bend the lead so that the lead will remain straight for more than 0.5mm from the case when soldering a crystal unit after bending. If not, the glass may be cracked (see Figures 5 and 6).
- (2) Always leave a length greater than 2.0mm when bending a lead after soldering (see Figure 7).







D ←→|2.0mm

Soldering directly to the case will reduce the degree of vacuum and may result in deterioration of the characteristics and may

Make the length from the case to the printed circuit board (L) longer than the case diameter (D) so that the lead wire

will not be pulled in case the crystal unit falls over.

#### 2. Precautions for mounting plastic molded products

- · If the board is deformed such as bending after mounting on the board, peeling of the soldered part between the crystal resonator and the board, the crack in the plastic molding, destruction of the internal element, etc. may occur. Especially when dividing the board on which it is mounted, there is a possibility that a large stress may be applied at the time of division. Please consider board layout and cutting method to minimize stress on products.
- When the product is automatically mounted on the board, if a large impact is applied to the crystal resonator, there is a possibility that characteristics may change / deteriorate or the product may be broken. When mounting automatically, please set conditions considering the shock to the crystal unit. Also, please conduct the mounting test beforehand and confirm that there is no influence on the characteristics to the crystal resonator.

Seiko Instruments Inc.

## **Quartz Crystal Unit Handling Precautions**

#### 3. Precautions for mounting ceramic package products

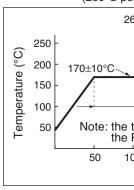
- division. Please consider board layout and cutting method to minimize stress on products.
- confirm that there is no influence on the characteristics to the crystal resonator.
- confirm that there is no influence on the crystal unit.
- consideration to the selection and handling of the tools to be used.

#### 4. SOLDERING

- Cylinder
- the crystal unit.

If crystal unit is unavoidably heated, heat the lead part at 300°C or lower for 5 seconds or less and please make sure to keep the case below 150°C.

Ceramic package. Plastic mold. Oscillator An example of the reflow temperature profile is shown as follows (see Figure 8).



#### 5. CLEANING

#### 6. MECHANICAL SHOCK

- ly before use if the crystal units have been dropped or subjected to an excessive mechanical shock.
- board by ultrasonic vibration before use.
- functions normally

· If the board is deformed such as bending after mounting on the board, peeling of the soldered part between the crystal resonator and the board, the crack in the ceramic package, destruction of the internal element, etc. may occur. Especially when dividing the board on which it is mounted, there is a possibility that a large stress may be applied at the time of

 When the product is automatically mounted on the board, if a large impact is applied to the crystal resonator, there is a possibility that characteristics may change / deteriorate or the product may be broken. When mounting automatically, please set conditions considering the shock to the crystal unit. Also, please conduct the mounting test beforehand and

The cracks may be occured in the soldered part by repeating the harsh temperature change for a long time when mounting the product on a board having a expansion coefficient different from that of the ceramics used in the crystal package. When using under such circumstances, please conduct test beforehand at your company and

· Ceramic packages are small and thin products. So when you repair the rework after mounting, please give due

The soldering position has to be at the lead wire more than 1.0mm away from the glass seal.

A long time for heating at high temperature may result in deterioration of the characteristics and may break

Example of SMD product soldering conditions (260°C peak: Lead-free products) 260°C peak 250±10°C -10±1sec 220°C~ 50+10sec 120+20sec Note: the temperature is the PCB surface temperature. 200 100 150 250 Time(sec.) Figure 8

· Since a small, thin crystal chip is used for tuning fork crystal units and the frequency approximates that of an ultrasonic cleaner, the crystal chip may break easily. Therefore, DO NOT perform ultrasonic cleaning.

· Quartz crystal units are designed to withstand a drop from 75cm onto a concrete at least 3 times. However, their crystal chips may break depending on the conditions when they are dropped. Ensure that the crystal unit functions normal-

 Unlike chip parts such as resistors, and capacitors, the SMD crystal unit has a crystal chip which is hermetically sealed inside. Therefore, check the influence of shock during automatic mounting or influence of deposition of case to the

· Avoid mounting crystal unit to the board with mechanical vibration source including ultrasonic vibration source. If the crystal unit is unavoidably mounted to the same board with mechanical vibration source, check that the crystal unit

## **Quartz Crystal Unit Handling Precautions**

## **Oscillation Circuit Design Precautions**

#### 7. Handling

· The crystal oscillator has an IC mounted on the backside of the package. Although it is resin-sealed, please do not directly touch the IC surface with tweezers, rigid tools and fixtures. If you scratch the IC, it may cause a malfunction, so be very careful.

#### 8. Usage Condition

Consider temperature and humidity in the product to be used, please use in the environment within the temperature range. When used in applications exposed to high humidity, malfunction due to dew condensation is a concern, so please take sufficient measures to prevent dew condensation.

#### 9. Precautions for Oscillator

Mounting

The oscillator has polarity, it may cause malfunctions or destruction. if mounting by the opposite direction.

- About the input terminals
- Please follow the specifications of each product when use the input terminal.
- Board wiring

Power supply line / Ground pattern line should use a thick pattern to reduce the impedance. Signal line should uses a thick pattern to reduce the impedance. It should be short for the distance to the connected IC.

For avoid noise effect, please make sure there is no pattern under crystal unit.

Noise

If excessive external noise is applied to the terminals, the issue such as latch-up phenomenon and electrostatic breakdown may be happened.

Heat stress

There is a risk of degradation of the crystal unit / IC due to a sudden temperature change. It should use under the specification.

Power supply time

For avoid malfunction, it should be careful power-on time.

#### 10. Precautions for handling reels

Crystal products are degraded in characteristics when exposed for long periods under high or low temperature environments. Then, it should store at normal temperature and normal humidity. Avoid storing for a long time and mount the crystal units immediately after unpacked.

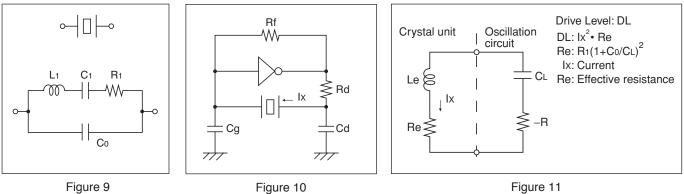
Normal temperature / humidity conditions: +15 to 35°C / 25 to 85%RH

· When delivered with tape reel, the tape reel may deform if large impact is applied.

#### 1. DRIVE LEVEL (DL)

The drive level of a crystal unit is shown by the level of the operating power or the current consumption (see Figures 9, 10, and 11).

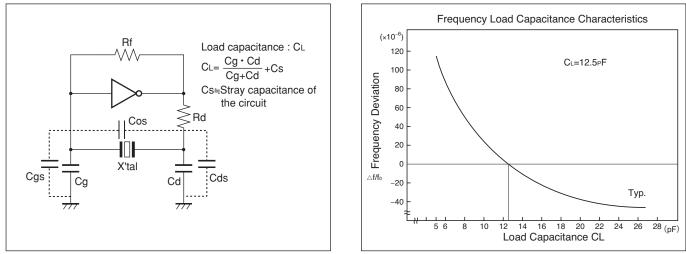
Operating the crystal unit at an excessive power level will result in the degradation of its characteristics, which may cause frequency instability or physical failure of the crystal chip. Design your circuit within absolute maximum drive level.



#### 2. OSCILLATION FREQUENCY AND LOAD CAPACITANCE (C, )

crystal unit (see Figure 12).

The oscillation frequency varies depending upon the load capacitance of the oscillation circuit. In order to obtain the desirable frequency accuracy, matching between the load capacitances of the oscillation circuit and the crystal unit is required. For the use of the crystal unit, match the load capacitances of the oscillation circuit with the load capacitances of the crystal unit.







The load capacitance ( $C_L$ ) is a parameter for determining the frequency of the oscillation circuit. The  $C_L$  is represented by an effective equivalent capacitance that is loaded from the oscillation circuit to both ends of the



#### 3. OSCILLATION ALLOWANCE

To ensure stable oscillation, the negative resistance of the circuit should be significantly larger than the equivalent series resistance (the oscillation allowance is large). Ensure that the oscillation allowance is at least five times as large as the equivalent series resistance.

#### **Oscillation Allowance Evaluation Method**

Add resistor "Rx" to the crystal unit in series and ensure that the oscillation starts or stops. The approximate negative resistance of the circuit is the value obtained by adding the effective resistance "Re" to the maximum resistance "Rx" when the oscillation starts or stops after gradually making Rx value larger.



I-RI is a value at least five times as large as the maximum equivalent series resistance (R1 max.) of the crystal unit. \*Re is the effective resistance value during oscillation.  $Re = R_1 (1 + \frac{C_0}{C_1})^2$ 

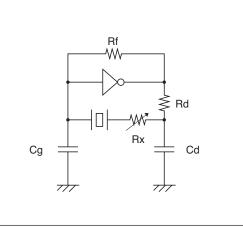


Figure 14

## Packing

#### LEAD TYPE PRODUCTS

After products are inserted in polyethylene bags, the bags are placed in boxes for shipping.

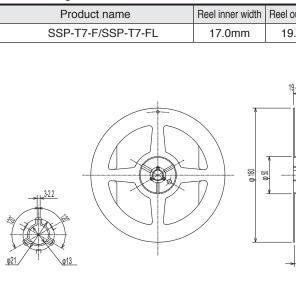
Product name	Quantity per lot	Quantity per bag	Quantity per box
VT-200-FL / VT-200-F / VT-150-F	10,000 pcs.	500 pcs	20 bags
VT-120-F / VTC-120-F	20,000 pcs.	1,000 pcs	20 bags

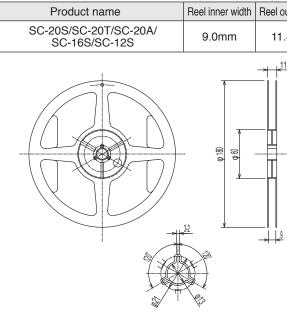
#### SMD PRODUCTS

Product name	
SSP-T7-F/SSP-T7-FL	
SC-32S/SC-32A/SC-32P/SC-20S/SC-20T/	
SC-20A/SH-32S	
SC-16S/SC-12S	

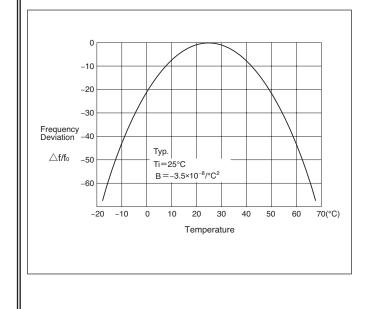
#### **TAPE AND REEL CONFIGURATION**

· Reel configuration





## FREQUENCY-TEMPERATURE CURVE



#### **Frequency Temperature Characteristics**

Frequency temperature characteristics of tuning fork crystals is shown by negative quadratic curve which has a peak at 25°C as per left graph.

Please make sure to consider the temperature range and frequency accuracy you need since magnitude of frequency variation becomes larger and larger as the temperature range becomes wider.

[Approximation formula of frequency temperature characteristics]

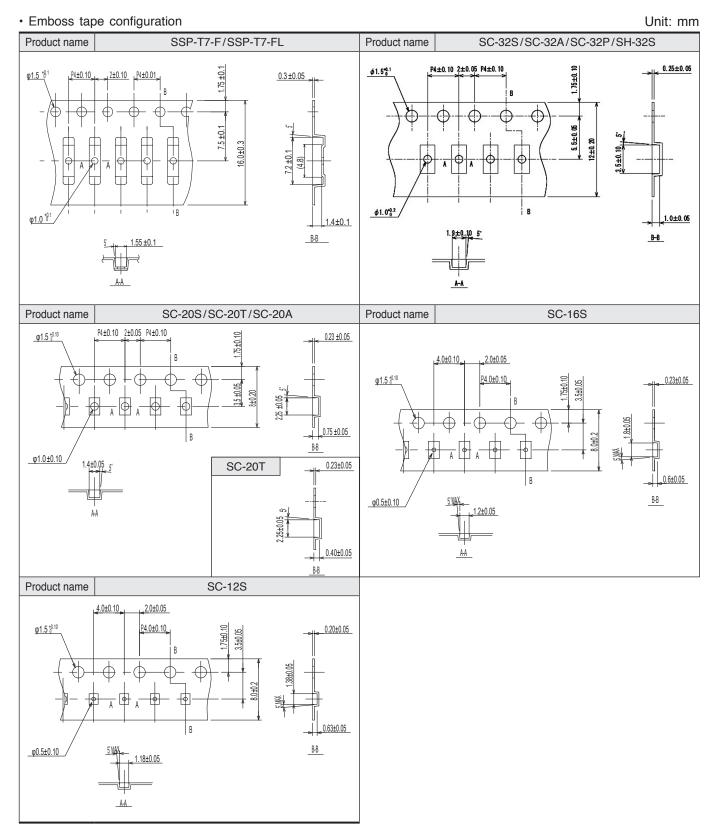
#### f\_tem=B (T-Ti)<sup>2</sup>

- B : Parabolic coefficient
- T : Given temperature
- Ti: Turnover temperature



Quantity per reel	
3,000 pcs.	
5,000 pcs	

outer width	Product name	Reel inner width	Reel outer width
.4mm	SC-32S/SC-32A/SC-32P/SH-32S	13.0mm	15.4mm
9.4±1,0			
outer width			
.4mm			
1 <u>1.4</u>			
<u>)</u>			



Precautions for handling reels

(1) Store at normal temperature and normal humidity (refer to standard conditions of JIS Z-8703 laboratory). Avoid storing for a long time and mount the crystal units immediately after unpacked. [Normal temperature: +15 to 35°C Normal humidity: 25 to 85%RH]

(2) Handle outside boxes and reels with care.

Tapes and reels may be deformed by external pressure.

Seiko Instruments Inc.

MEMO

Seiko Instruments Inc.